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The technical content of this austriamicrosystems datasheet is still valid.

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AS1331

300mA Buck-Boost Synchronous DC/DC Converters

1 General Description

This special device is a synchronous buck-boost DC/DC converter which can handle input voltages above, below, or equal to the output voltage.

Due to the internal structure of the AS1331 which is working continuously through all operation modes this device is ideal for dual or triple cell alkaline/NiCad/NiMH as well as single cell Li-Ion battery applications.

Because of the implemented Power Save Mode, the solution footprint and the component count is minimized and also over a wide range of load currents a high conversion efficiency is provided.

The device includes two N-channel MOSFET switches and two P-channel switches. Also following features are implemented: a quiescent current of typically 22µA (ideal for battery power applications), a shutdown current less than 1µA, current limiting, thermal shutdown and output disconnect.

The AS1331 is available in a 10-pin 3x3mm TDFN package with fixed and adjustable output voltage.

2 Key Features

- Input Voltage Range: 1.8V to 5.5V
- Output Voltages:
  - Fixed: 2.5V, 3.0V, 3.3V
  - Adjustable: 2.5V to 3.3V
- Output Current: 300mA @ 3.3V
- Up to 90% efficiency
- Power Good
- Output Disconnection in Shutdown
- Automatic transition between Buck and Boost mode
- Ultra Low Quiescent Current: 22µA, Shutdown Current <1µA (Active Low)
- Short-Circuit Protection
- Low Battery detection
- Over Temperature Protection
- 10-pin 3x3mm TDFN package

3 Applications

The AS1331 is an ideal solution for handheld computers, handheld instruments, portable music players and PDA's. Two and three cell Alkaline, NiCd or NiMH or single cell Li battery powered products.

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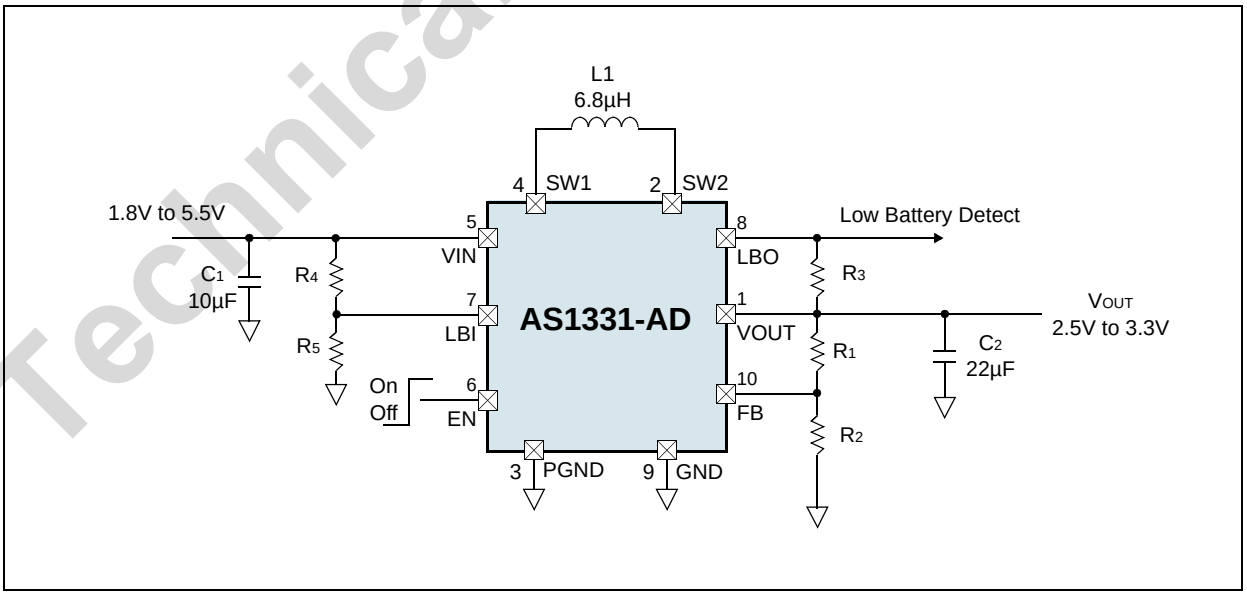
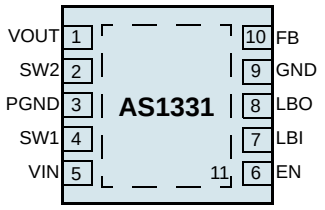
Figure 1. AS1331 - Typical Application Diagram



4 Pin Assignments

Figure 2. Pin Assignments (Top View)



Pin Descriptions

Table 1. Pin Descriptions

Pin Name	Pin Number	Description
VOUT	1	**Output of the Buck/Boost Converter.**
SW1	2	**Buck/Boost Switch Pin.** Connect the inductor from SW1 to SW2
PGND	3	**Power Ground.** Both GND pins must be connected.
SW2	4	**Buck/Boost Switch Pin.** Connect the inductor from SW1 to SW2. An optional Schottky diode can be connected between this pin and VOUT to increase efficiency.
VIN	5	**Input Supply Pin.** A minimum 2.2µF capacitor should be placed between VIN and GND.
EN	6	**Enable Pin**. Logic controlled shutdown input. 1 = Normal operation; 0 = Shutdown; quiescent current <1µA.
LBI	7	**Low Battery Comperator Input**. 1.25V Threshold. May not be left floating. If connected to GND LBO is working as Output Power okay.
LBO	8	**Low Battery Comperator Output**. This open-drain output is low when the voltage on LBI is less than 1.25V.
GND	9	**Ground.** Both GND pins must be connected.
FB	10	**Feedback Pin**. Feedback input for the adjustable version. Connect a resistor divider tap to this pin. The output voltage can be adjusted from 2.5V to 3.3V by: $V_{OUT} = 1.25V[1 + (R_1/R_2)]$ **Note:** For the fixed Output Voltage Version contact this pin to V_{OUT}.
NC	11	**Exposed Pad.** This pad is not connected internally. It can be used for ground connection between GND and PGND.

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5 Absolute Maximum Ratings

Stresses beyond those listed in Table 2 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in Electrical Characteristics on page 4 is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 2. Absolute Maximum Ratings

Parameter	Min	Max	Units	Notes
SW1, SW2, VIN, VOUT, EN	-0.3	+7	V	
PGND to GND	-0.3	+0.3	V	
SW1, SW2	-0.3	+7	V	
ESD	4		kV	*HBM MIL-Std. 883E 3015.7* methods
Thermal Resistance θ_{JA}	+33		ºC/W	
Junction Temperature	+150		ºC	
Operating Temperature Range	-40	85	ºC	
Storage Temperature Range	-65	+125	ºC	
Package Body Temperature	+260		ºC	The reflow peak soldering temperature (body temperature) specified is in accordance with *IPC/JEDEC J-STD-020D "Moisture/Reflow Sensitivity Classification for Non-Hermetic Solid State Surface Mount Devices".* The lead finish for Pb-free leaded packages is matte tin (100% Sn).

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6 Electrical Characteristics

V_{IN} = 3.6V, V_{OUT} = 3.3V, T_{AMB} = -40°C to +85ºC. Typical values are at T_{AMB} = +25ºC. Unless otherwise specified.

Table 3. Electrical Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Input						
V_{IN}	Input Voltage Range		1.8		5.5	V
	Minimum Startup Voltage	I_{LOAD} < 1mA		1.6	1.8	V
V_{UV}	Undervoltage Lockout Threshold[1]	V_{IN} decreasing	1.5	1.6	1.7	V
Regulation						
V_{OUT}	Output Voltage Adjustable Version		2.50		3.30	V
	Output Voltage 3.3V	No Load	3.201	3.3	3.399	V
	Output Voltage 3.0V		2.910	3.0	3.090	V
	Output Voltage 2.5V		2.425	2.5	2.575	V
V_{FB}	FB Voltage Adjustable version	No Load	1.212	1.25	1.288	V
I_{FB}	FB Input Current Adjustable Version	V_{FB} = 1.3V, T_{AMB} = 25°C		1	100	nA
	V_{OUT} Lockout Threshold[2]	Rising Edge	2.0	2.15	2.3	V
Operating Current						
I_Q	Quiescent Current V_{IN}	V_{IN} = 5V		2	6	µA
	Quiescent Current V_{OUT}	V_{IN} = 5V, V_{OUT} = 3.6V, V_{FB} = 1.3V		20	32	µA
I_{SHDN}	Shutdown Current	EN = 0V, V_{OUT} = 0V, *T_{AMB} = +25ºC*		0.01	1	µA
Switches						
I_{MOS}	MOS Switch Leakage	V_{IN} = 5V, T_{AMB}=25°C, Switches A-D		0.01	1	µA
R_{ON}	NMOS B, C	V_{IN} = 5V		0.13		Ω
	PMOS A	V_{IN} = 5V		0.17		Ω
	PMOS D	V_{OUT} = 3.3V		0.21		Ω
I_{PEAK}	Peak Current Limit	L = 6.8µH, V_{IN} = 5V	450	600	750	mA
Enable						
V_{ENH}	EN Input High		1.4			V
V_{ENL}	EN Input Low				0.4	V
I_{EN}	EN Input Current	EN = 5.5V, T_{AMB} = 25°C		1	100	nA
Low Battery & Power-OK						
V_{LBI}	LBI Threshold	Falling Edge	1.212	1.25	1.288	V
	LBI Hysteresis			10		mV
	LBI Leakage Current	LBI = 5.5V, T_{AMB} = 25°C		1	100	nA
	LBO Voltage Low[3]	I_{LBO} = 1mA		0.05	0.2	V
	LBO Leakage Current	LBO = 5.5V, T_{AMB} = 25°C		1	100	nA
	Power-OK Threshold	LBI = 0V, Falling Edge	90	92.5	95	%

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Table 3. Electrical Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Thermal Protection						
	Thermal Shutdown	10°C Hysteresis		145		°C

1. If the input voltage falls below this value during normal operation the device goes in startup mode.
2. The regulator is in startup mode until this voltage is reached. Caution: Do not apply full load current until the device output > 2.3V
3. LBO goes low in startup mode as well as during normal operation if:
   1) The voltage at the LBI pin is below LBI threshold.
   2) The voltage at the LBI pin is below 0.1V and VOUT is below 92.5% of its nominal value.

Note: All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

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7 Typical Operating Characteristics

Circuit of Figure 24 on page 12, VIN = 2.4V, VOUT = 3.3V, TAMB = +25°C, unless otherwise specified.

Figure 3. Efficiency vs. Output Current; VOUT = 2.5V

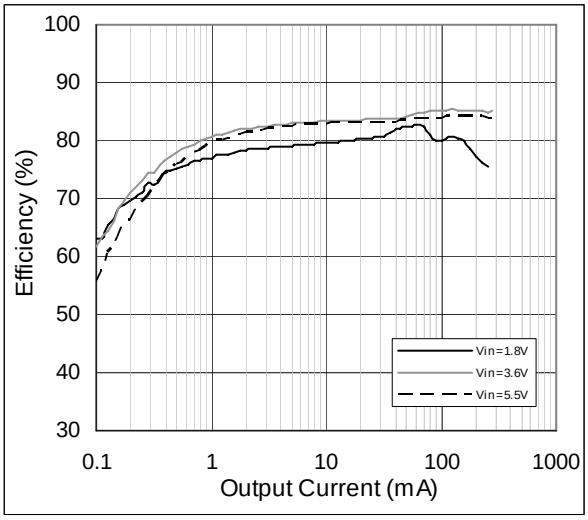

Figure 4. Efficiency vs. Output Current; VOUT = 3.0V

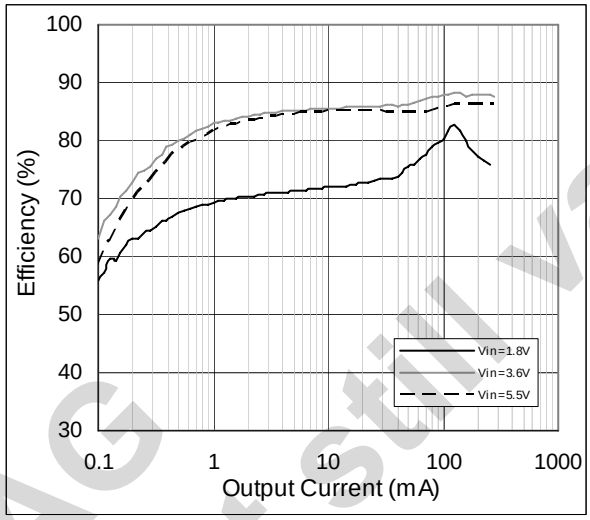

Figure 5. Efficiency vs. Output Current; VOUT = 3.3V

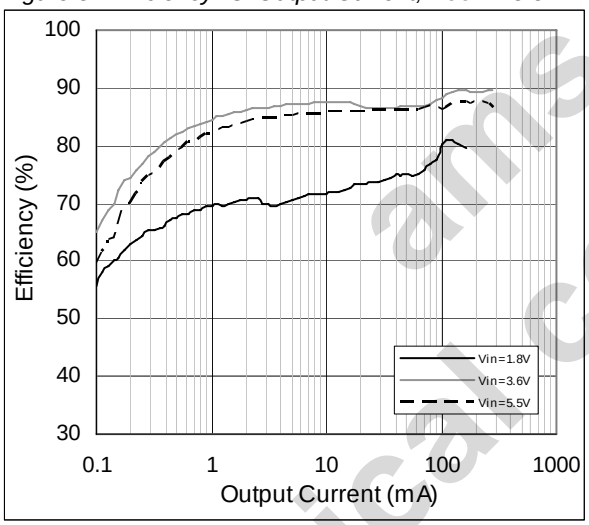

Figure 6. Efficiency vs. Input Voltage

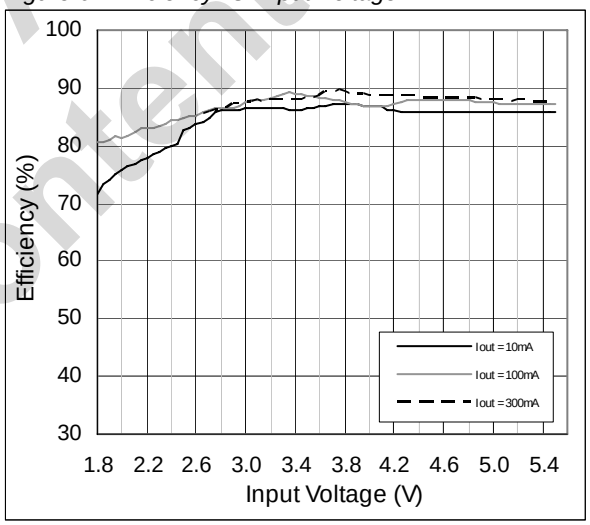

Figure 7. IOUT max vs. Input Voltage

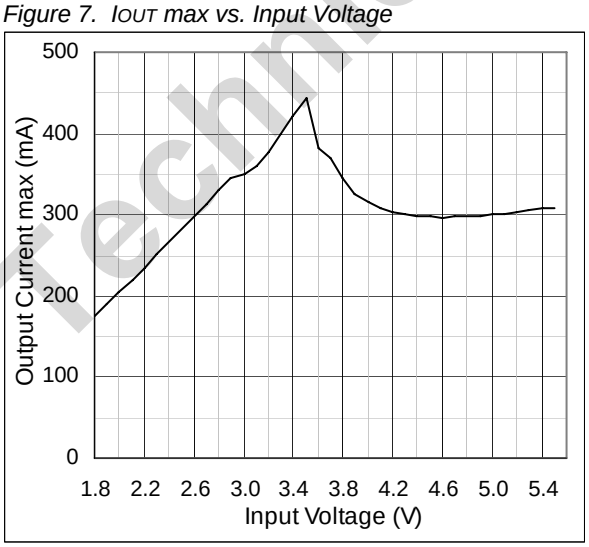

Figure 8. Sleep Currents vs. Input Voltage

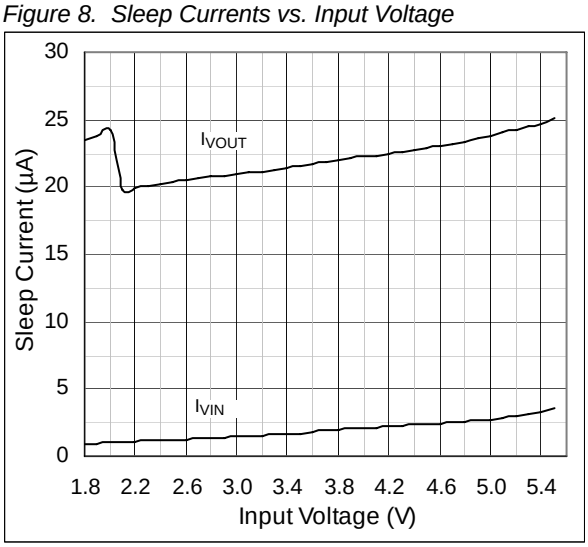

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Figure 9. I_{IN} Short Circuit vs. Input Voltage

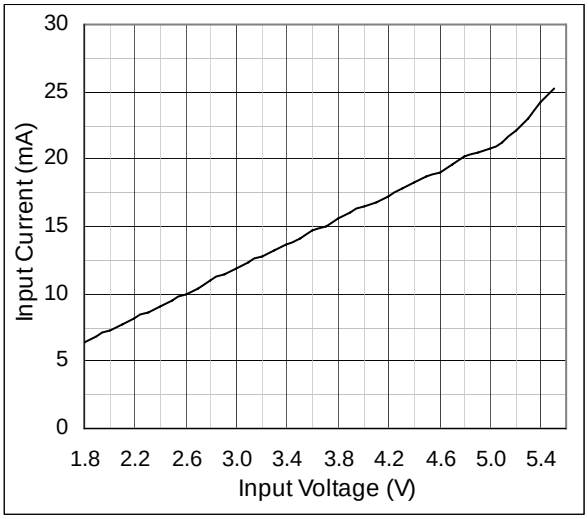

Figure 10. V_{OUT} Ripple vs. Input Voltage

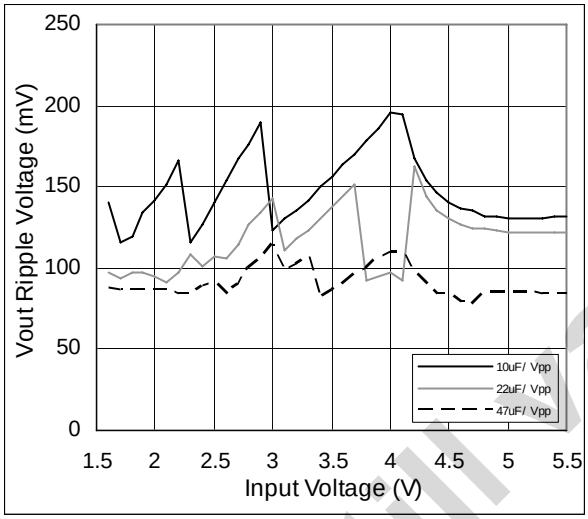

Figure 11. Load Regulation vs. Load Current

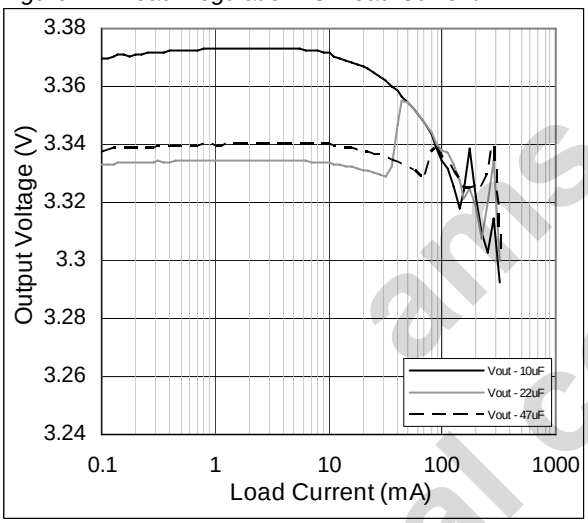

Figure 12. V_{OUT} Regulation vs. Temperature

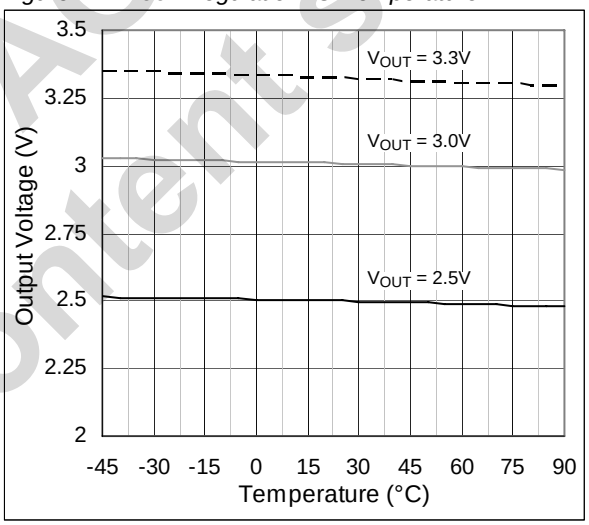

Figure 13. I_{FB} vs. Temperature; V_{IN} = 5V

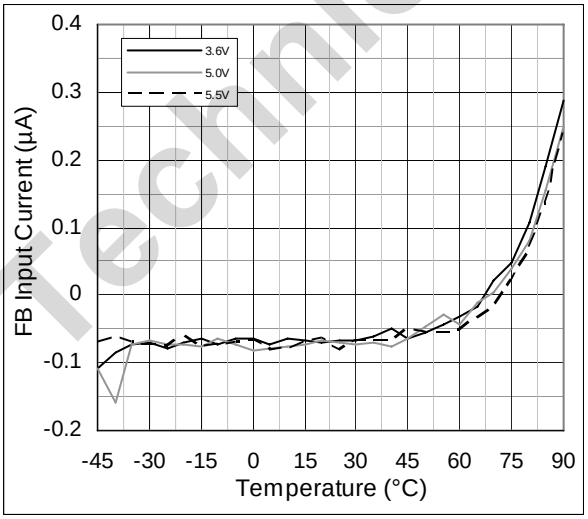

Figure 14. EN Pin Threshold

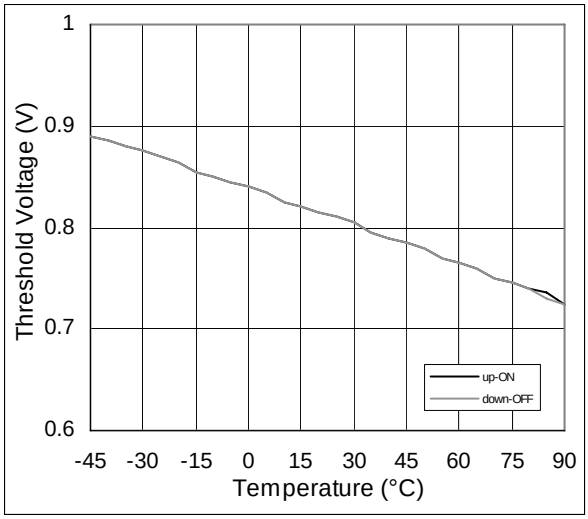

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Figure 15. V_{IN} = 4.4V, V_{OUT} = 3.3V, *I_{OUT} = 200mA*

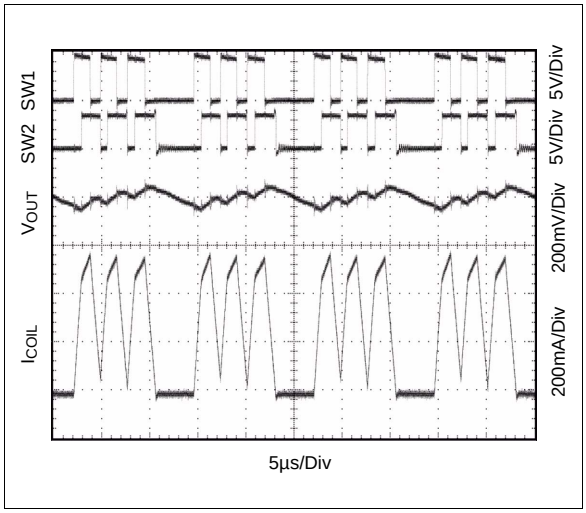

Figure 16. V_{IN} = 4.4V, V_{OUT} = 3.3V, *I_{OUT} = 50mA*

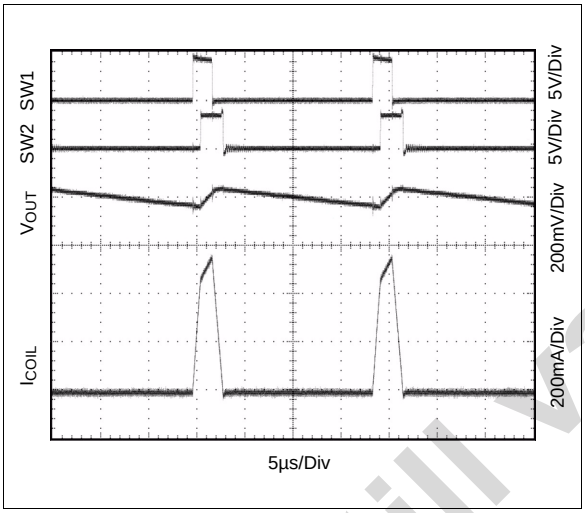

Figure 17. V_{IN} = 3.6V, V_{OUT} = 3.3V, *I_{OUT} = 200mA*

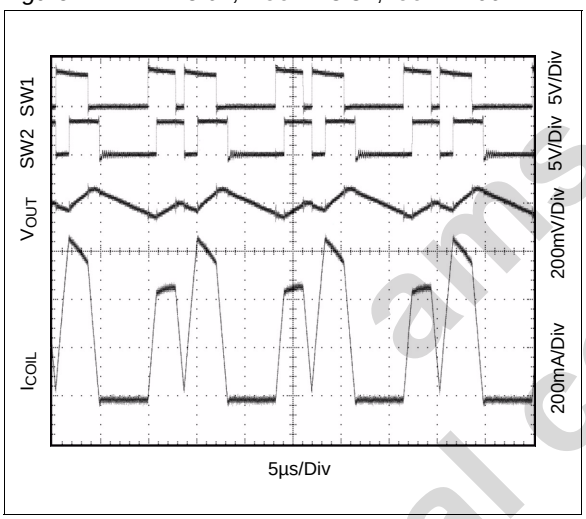

Figure 18. V_{IN} = 3.6V, V_{OUT} = 3.3V, *I_{OUT} = 50mA*

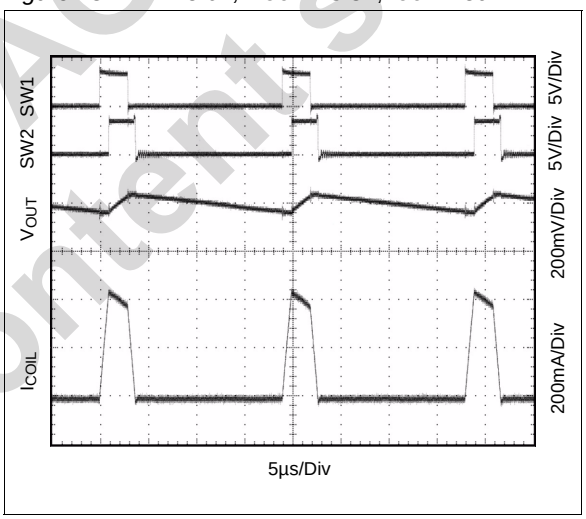

Figure 19. V_{IN} = 2.5V, V_{OUT} = 3.3V, *I_{OUT} = 200mA*

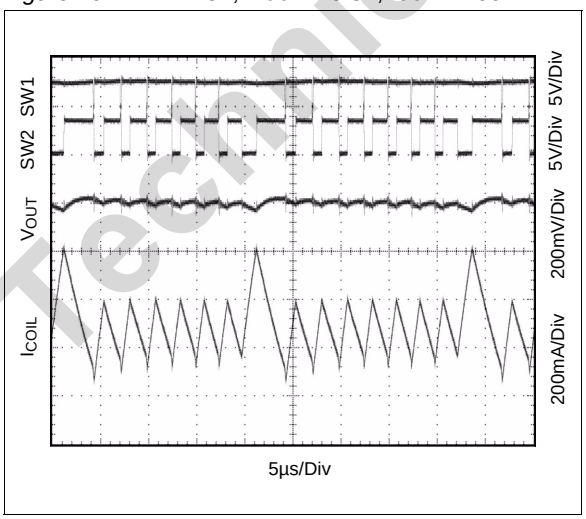

Figure 20. V_{IN} = 2.5V, V_{OUT} = 3.3V, *I_{OUT} = 50mA*

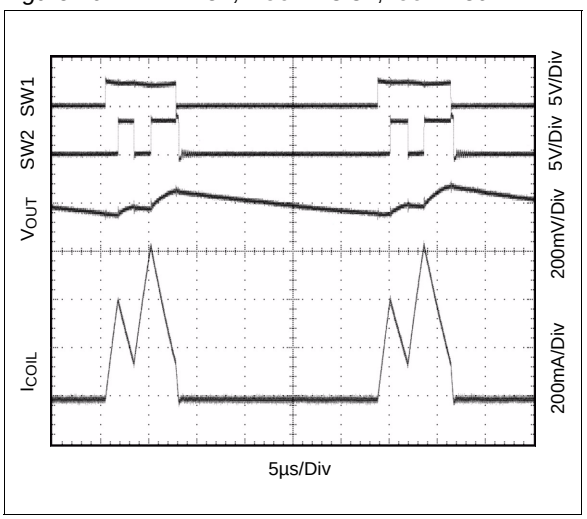

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Figure 21. Shorted Output; V_{IN} = 3.6V

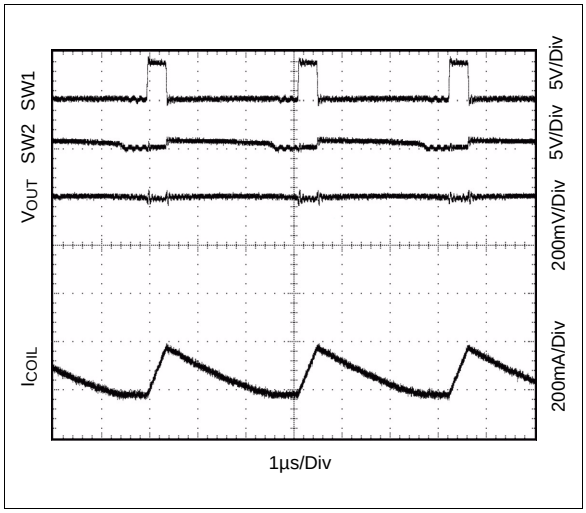
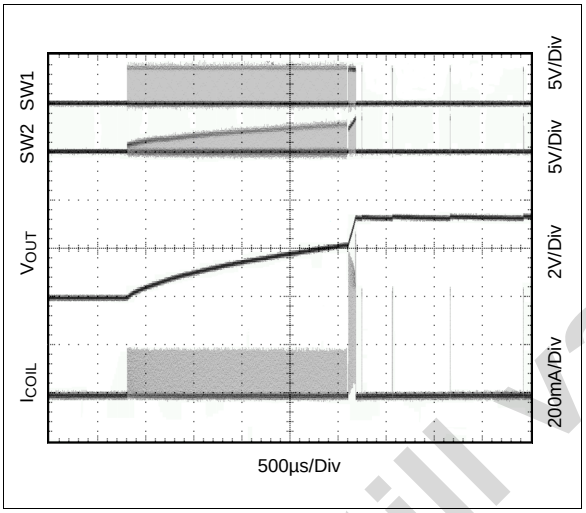


Figure 22. Startup; V_{IN} = 3.6V, R_{load} = 3.3kΩ



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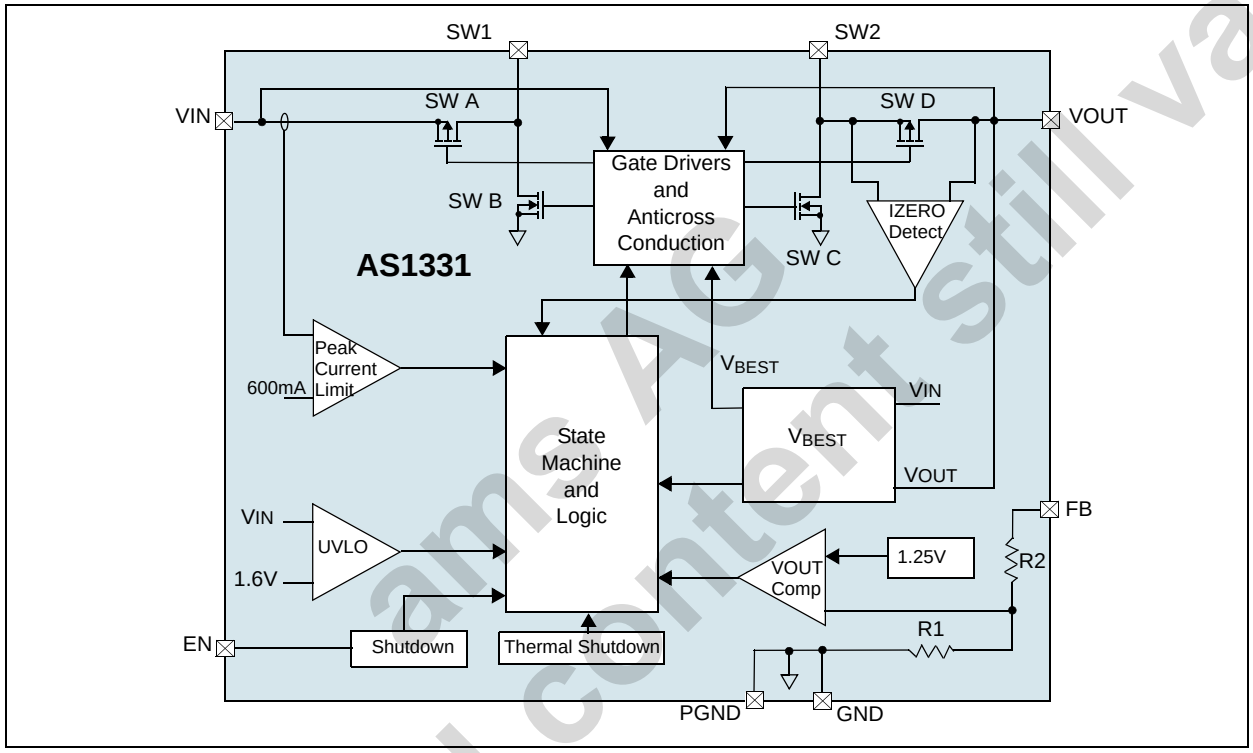
8 Detailed Description

The synchronous buck-boost converter AS1331 uses a Power Save Mode control technique to reach a high efficiency over a wide dynamic range of load currents. The output voltage is monitored by a comparator with 3% accuracy. The Power Save Mode puts the device into “sleep mode” when VOUT is above its programmed reference threshold. Meaning, the switching is stopped and only quiescent current is drawn from the power source. The switching is started again when VOUT drops below the reference threshold and the output capacitor is charged again.

The numbers of current pulses which are necessary to load the output capacitor are set by the value of the output capacitor, the load current, and the comparator hysteresis (~1%).

Figure 23. AS1331 - Block Diagram - Fixed Output Voltage



Modes of Operation

When VOUT drops below the reference threshold, the AS1331 switches on the transistors SW A and SW C until the inductor current reaches approximately 400mA. In the next step SW A and SW D are closed and depending on the difference between VIN and VOUT the inductor current raises, falls or stays constant.

VIN > VOUT: The inductor current is going up to 600mA.

VIN ~ VOUT: The device stops after 2µs.

VIN < VOUT: The inductor current falls down to 0mA.

If the inductor current is not 0mA, the transistors SW B and SW D are closed to ramp down the current to zero. If VOUT is still below the threshold voltage the next cycle is started. If IMAX (600mA) wasn’t reached in the previous cycle, SW A and SW D are closed until the inductor current is 600mA.

Note: The 4-switch-mode (SW A+SW C => SW B+SW D => SW A + SW C...) and also the buck-mode (SW A+SW D => SW B+SW D => SW A+SW D...) are never used.

Start-Up Mode

At start-up the switch SW D is disabled and its diode is used to transfer current to the output capacitor until VOUT reaches approximately 2.15V. The inductor current is controlled by an alternate algorithm during start-up.

Note: Do not apply loads >1mA until VOUT = 2.3V is reached.

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Other AS1331 Features

Shutdown

The part is in shutdown mode while the voltage at pin EN is below 0.4V and is active when the voltage is higher than 1.4V.

Note: EN can be driven above VIN or VOUT, as long as it is limited to less than 5.5V.

Output Disconnect and Inrush Limiting

During shutdown VOUT is going to 0V so that no current from the input source is running thru the device. The inrush current is also limited at turn-on mode to minimize the surge currents seen by the input supply. These features of the AS1331 are realized by opening both P-channel MOSFETs of the rectifiers, allowing a true output disconnect.

Power-OK and Low-Battery-Detect Functionality

LBO goes low in startup mode as well as during normal operation if:

- The voltage at the LBI pin is below LBI threshold (1.25V). This can be used to monitor the battery voltage.
- LBI pin is connected to GND and VOUT is below 92.5% of its nominal value. LBO works as a power-OK signal in this case.

The LBI pin can be connected to a resistive-divider to monitor a particular definable voltage and compare it with a 1.25V internal reference. If LBI is connected to GND an internal resistive-divider is activated and connected to the output. Therefore, the Power-OK functionality can be realised with no additional external components.

The Power-OK feature is not active during shutdown and provides a power-on-reset function that can operate down to VIN = 1.8V. A capacitor to GND may be added to generate a power-on-reset delay. To obtain a logic-level output, connect a pull-up resistor from pin LBO to pin VOUT. Larger values for this resistor will help to minimize current consumption; a 100kΩ resistor is perfect for most applications (see Figure 25 on page 12).

For the circuit shown in the left of Figure 24 on page 12, the input bias current into LBI is very low, permitting large-value resistor-divider networks while maintaining accuracy. Place the resistor-divider network as close to the device as possible. Use a defined resistor for R5 and then calculate R4 as:

$$R_4 = R_5 \cdot \left(\frac{V_{IN}}{V_{LBI}} - 1\right) \qquad \textit{(EQ 1)}$$

Where:

V_{LBI} (the internal sense reference voltage) is 1.25V.

In case of the LBI pin is connected to GND, an internal resistor-devider network is activated and compares the output voltage with a 92.5% voltage threshold. For this particular Power-OK application, no external resistive components are necessary.

Thermal Shutdown

To prevent the AS1331 from short-term misuse and overload conditions the chip includes a thermal overload protection. To block the normal operation mode all switches will be turned off. The device is in thermal shutdown when the junction temperature exceeds 145°C. To resume the normal operation the temperature has to drop below 135°C.

A good thermal path has to be provided to dissipate the heat generated within the package. Otherwise it's not possible to operate the AS1331 at its useable maximal power. To dissipate as much heat as possible away from the package into a copper plane with as much area as possible, it's recommended to use multiple vias in the printed circuit board. It's also recommended to solder the Exposed Pad (pin 11) to the GND plane.

Note: Continuing operation in thermal overload conditions may damage the device and is considered bad practice.

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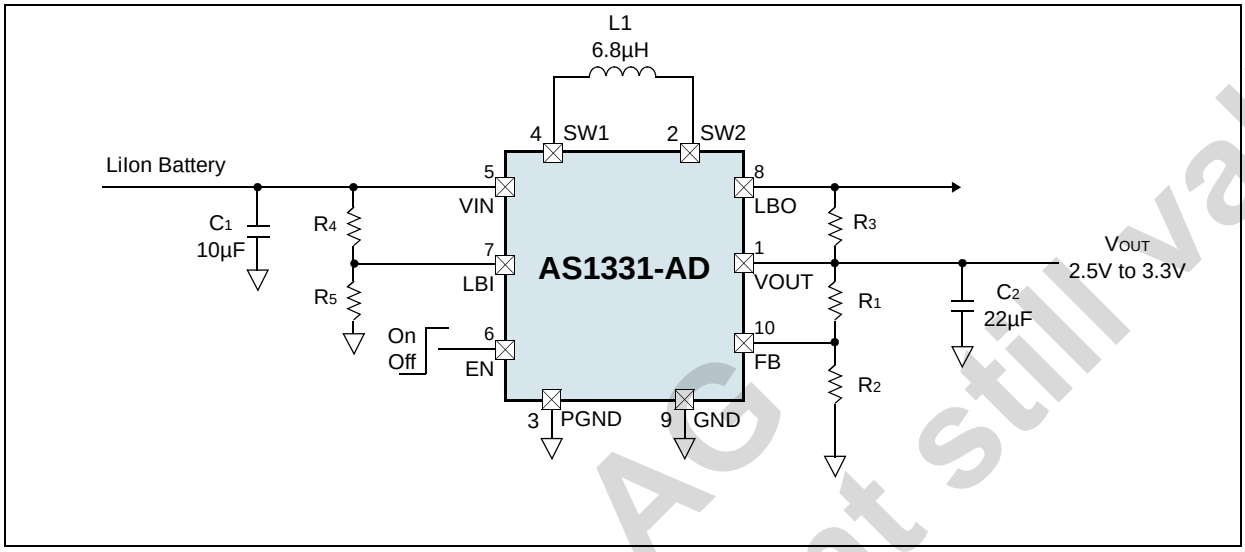
Output Voltage Selection

The AS1331 is available in two versions (see Ordering Information on page 15). One version can only operate at one fixed output voltage (see Figure 25) and the other version can operate with user-adjustable output voltages from 2.5V to 3.3V by connecting a voltage divider between the pins VOUT and FB (see Figure 24).

Figure 24. LiIon to Adjustable Output Voltage



The output voltage can be adjusted by selecting different values for R1 and R2.

Calculate VOUT by:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_1}{R_2}\right) \quad \textit{(EQ 2)}$$

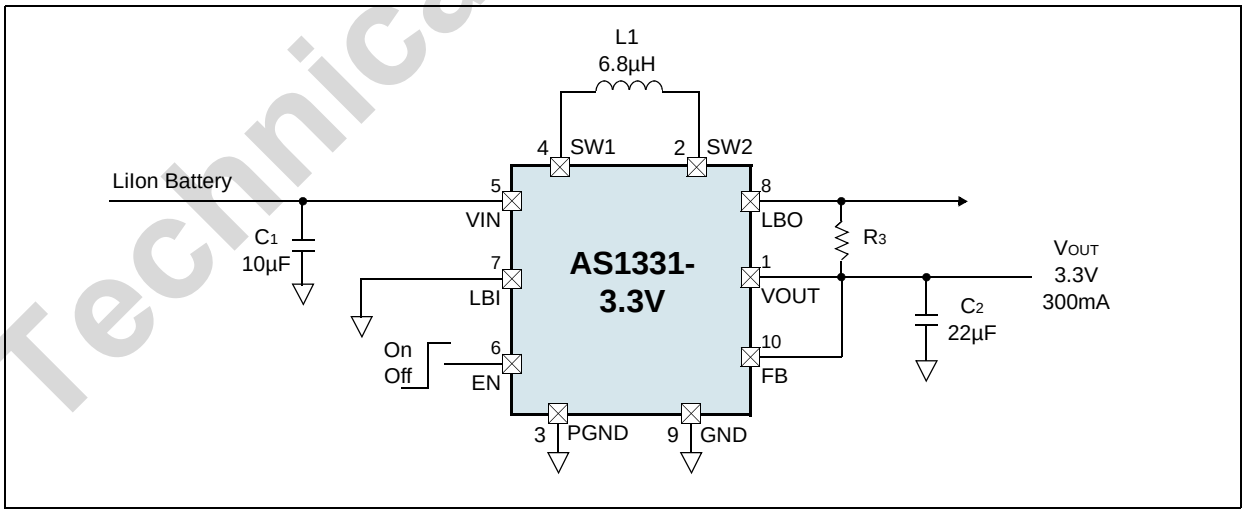
Where:

VFB = 1.25V, VOUT = 2.5V to 3.3V;

R2 (the predefined resistor in the resistor devider) should be ≤ 270kΩ.

R3 (the Pull-up resistor for the LBO pin) should be ~100kΩ.

Figure 25. LiIon to 3.3V with POK - Fixed Output Voltage



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9 Application Information

Component Selection

Only three power components are required to complete the design of the buck-boost converter. For the adjustable version VOUT programming resistors are needed. The high operating frequency and low peak currents of the AS1331 allow the use of low value, low profile inductors and tiny external ceramic capacitors.

Inductor Selection

For best efficiency, choose an inductor with high frequency core material, such as ferrite, to reduce core losses. The inductor should have low DCR (DC resistance) to reduce the I²R losses, and must be able to handle the peak inductor current without saturating. A 6.8µH inductor with a >600mA current rating and <400mΩ DCR is recommended.

Table 4. Recommended Inductors

Part Number	L	DCR	Current Rating	Dimensions (L/W/T)	Manufacturer
LPS3015-682M	6.8µH	300mΩ	0.89A	3.0x3.0x1.5mm	Coilcraft www.coilcraft.com
EPL2014-682M	6.8µH	287mΩ	0.80A	2.0x2.0x1.4mm	
XPL2010-682M	6.8µH	336mΩ	0.73A	2.0x1.9x1.0mm	

Capacitor Selection

The buck-boost convertor requires two capacitors. Ceramic X5R or X7R types will minimize ESL and ESR while maintaining capacitance at rated voltage over temperature. The VIN capacitor should be at least 2.2µF. The VOUT capacitor should be between 10µF and 47µF. A larger output capacitor should be used if lower peak to peak output voltage ripple is desired. A larger output capacitor will also improve load regulation on VOUT. See Table 5 for a list of capacitors for input and output capacitor selection.

Table 5. Recommended Input Capacitor

Part Number	C	TC Code	Rated Voltage	Dimensions (L/W/T)	Manufacturer
GRM188R61A225KE34	2.2µF	X5R	10V	0603, T=0.87mm	Murata www.murata.com
GRM188R60J475KE19	4.7µF	X5R	6.3V	0603, T=0.87mm	
GRM219R60J106KE19	10µF	X5R	6.3V	0805, T=0.95mm	

Table 6. Recommended Output Capacitor

Part Number	C	TC Code	Rated Voltage	Dimensions (L/W/T)	Manufacturer
GRM21BR61A106KE19	10µF	X5R	10V	0805, T=1.35mm	Murata www.murata.com
GRM319R61A106KE19	10µF	X5R	10V	1206, T=0.95mm	
GRM319R61A106KE19	10µF	X5R	10V	1210, T=0.95mm	
GRM31CR61C226KE15	22µF	X5R	16V	1206, T=1.8mm	
GRM31CR60J475ME19	47µF	X5R	6.3V	1206, T=1.75mm	

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10 Package Drawings and Markings

The device is available in a 10-pin 3x3mm TDFN package.

Figure 26. 10-pin 3x3mm TDFN package Diagram

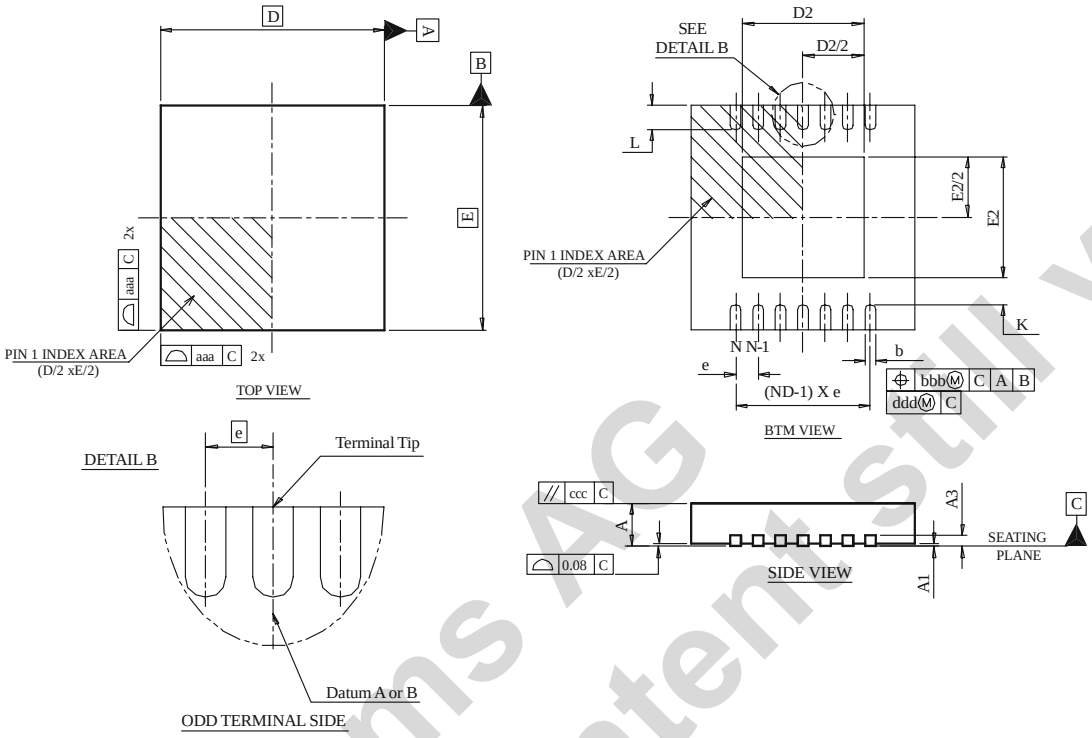

Table 7. 10-pin 3x3mm TDFN package Dimensions

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	0.70	0.75	0.80	D BSC		3.00	
A1	0.00	0.02	0.05	E BSC		3.00	
A3		0.20 REF		D2	2.20		2.70
L1	0.03		0.15	E2	1.40		1.75
L2			0.13	L	0.30	0.40	0.50
aaa		0.15		K	0.20		
bbb		0.10		b	0.18	0.25	0.30
ccc		0.10		e		0.50	
ddd		0.05		N		10	
eee		0.08		ND		5	
ggg		0.10		θ	0°		14°

Note:

1. Figure 26 is shown for illustration only.
2. All dimensions are in millimeters, angle is in degrees.
3. Dimensioning and tolerancing conform to *ASME Y14.5M-1994*.
4. N is the total number of terminals.
5. Terminal #1 identifier and terminal numbering convention shall conform to JESD 95-1 SPP-012. Details of terminal #1 identifier are optional, but must be located within the area indicated. The terminal #1 identifier may be either a mold, embedded metal or mark feature.
6. Dimension b applies to metallized terminal and is measured between 0.15 and 0.30mm from terminal tip.
7. ND refers to the maximum number of terminals on D side.
8. Unilateral coplanarity zone applies to the exposed heat sink slug as well as the terminals.

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11 Ordering Information

The device is available as the standard products shown in Table 8.

Table 8. Ordering Information

Ordering Code	Marking	Output	Description	Delivery Form	Package
AS1331-BTDT-AD	ASRP	adjustable	300mA Buck-Boost Synchronous DC/DC Converters	Tape and Reel	10-pin 3x3mm TDFN
AS1331-BTDT-25*	ASRR	2.5V	300mA Buck-Boost Synchronous DC/DC Converters	Tape and Reel	10-pin 3x3mm TDFN
AS1331-BTDT-30*	ASRT	3.0V	300mA Buck-Boost Synchronous DC/DC Converters	Tape and Reel	10-pin 3x3mm TDFN
AS1331-BTDT-33	ASRU	3.3V	300mA Buck-Boost Synchronous DC/DC Converters	Tape and Reel	10-pin 3x3mm TDFN

***** on request

Note: All products are RoHS compliant and Pb-free.
Buy our products or get free samples online at ICdirect: http://www.austriamicrosystems.com/ICdirect

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